NSN 5961-01-587-3554

Transistor - Page 1 of 1

Demilitarization:

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-587-3554 **Inclosure Material:** Plastic and metal **Overall Length:** 106.4 millimeters **Overall Height:** 36.5 millimeters **Overall Width:** 61.4 millimeters **End Application:** Rectifier **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 2.0 emitter to collector voltage, dc **Current Rating Per Characteristic:** 400.00 amperes forward current, dc **Product Name:** Inavy: transistor; cage: igbt module **Special Features:** Isolated copper baseplate using dbc direct copper bonding technology; mos input (voltage controlled); n channel, homogeneous si; low inductance case; very low tail current with low temperature dependence; high short circuit capability; latch-up free; fast and soft cal diodes; large clearance (12mm) and creepage distances (20mm) **Terminal Type And Quantity:** 4 quick disconnect, female Shelf Life: N/a **Unit Of Measure:**